



APTM100A13DG Information

Heisener.com

Part Number APTM100A13DG

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 1000V 65A SP6

Package SP6

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APTM100A13DG Specifications

Manufacturer Part Number	APTM100A13DG
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	SP6
Series	-
FET Type	2 N-Channel (Half Bridge)
FET Feature	Standard
Drain to Source Voltage (Vdss)	1000V (1kV)
Current - Continuous Drain (Id) @ 25°C	65A
Rds On (Max) @ Id, Vgs	156 mOhm @ 32.5A, 10V
Vgs(th) (Max) @ Id	5V @ 6mA
Gate Charge (Qg) (Max) @ Vgs	562nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	15200pF @ 25V
Power - Max	1250W
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	SP6
Supplier Device Package	SP6
	Report errors?

APTM100A13DG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM100A13DG Payment Methods



















APTM100A13DG Shipping Methods













If you have any question about APTM100A13DG, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com